Docket No.

244683US2S

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: Kenji TSUCHIDA

SERIAL NO: New Application

GAU:

FILED:

Herewith

EXAMINER:

FOR:

MRAM HAVING CURRENT PEAK SUPPRESSING CIRCUIT

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.97

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

Applicant(s) wish to disclose the following information.

REFERENCES

- The applicant(s) wish to make of record the references listed on the attached form PTO-1449. Copies of the listed references are attached, where required, as are either statements of relevancy or any readily available English translations of pertinent portions of any non-English language references.
- ☐ A check or credit card payment form is attached in the amount required under 37 CFR §1.17(p).

RELATED CASES

- Attached is a list of applicant's pending application(s) or issued patent(s) which may be related to the present application. A copy of the patent(s), together with a copy of the claims and drawings of the pending application(s) is attached along with PTO 1449.
- A check or credit card payment form is attached in the amount required under 37 CFR §1.17(p).

CERTIFICATION

- ☐ Each item of information contained in this information disclosure statement was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this statement.
- □ No item of information contained in this information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to the knowledge of the undersigned, having made reasonable inquiry, was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing of this statement.

DEPOSIT ACCOUNT

Please charge any additional fees for the papers being filed herewith and for which no check or credit card payment is enclosed herewith, or credit any overpayment to deposit account number <u>15-0030</u>. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND, MAIER & NEUSTADT, P.C.

Marvin J. Spivak

Registration No. 24,913

C. Irvin McClelland Registration Number 21,124

Customer Number

22850

Tel. (703) 413-3000 Fax. (703) 413-2220 (OSMMN 05/03) DOCKET NO: 244683US2S

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STATEMENT OF RELEVANCY

Sheet <u>1</u> of <u>1</u>

Reference AA (US 6,356,477) on Form PTO- 1449:

This reference shows similar MRAM circuit structure.

Reference AW on Form PTO- 1449:

This publication is referred to in the specification. See page 4, line 10.

Form PTO 1449		U.S. DEPARTMENT		ATTY DOCKET NO. 244683US2S		SERIAL N	10.		
(Modified)		PATENT AND TRAD	EMARK OFFICE			New Application			
				APPLICANT					
LIST OF	REFER	RENCES CITED BY API	PLICANT	Kenji TSUCHIDA					
				FILING DATE		GROUP			
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U.S. PATENT DOCUMENTS									
EXAMINER		DOCUMENT	DATE	NAME	CLASS	CLASS SUB FILING DATE			
INITIAL		NUMBER			02.00	CLASS IF APPROPRIATE			
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OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)									
	AW	Roy SCHEUERLEIN, et al., "A 10ns Read and Write Non-Volatile Memory Array Using a Magnetic Tunnel Junction and FET Switch in each Cell", ISSCC 2000 DIGEST OF TECHINCAL PAPER, INTERNATIONAL SOLID-STATE CIRCUITS CONFERENCE, SESSION 7 / TD: EMERGING MEMORY & DEVICE TECHNOLOGIES, February 8, 2000, pgs. 128-129							
	AX	Takeshi HONDA, et al., "MRAM-Writing Circuitry to Compensate for Thermal-Variation of Magnetization-Reversal Current", 2002 SYMPOSIUM ON VLSI CIRCUITS DIGEST OF TECHNICAL PAPERS, 2002, 1 page							
	AY								
	AZ				Additional References sheet(s) attached				
Examiner						Date Considered			
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.									